

Formation of metallic NbSe₂ nanotubes and nanofibers

T. Tsuneta^{a,*}, T. Toshima^a, K. Inagaki^a, T. Shibayama^a, S. Tanda^a, S. Uji^b,
M. Ahlskog^c, P. Hakonen^c, M. Paalanen^c

^a Department of Applied Physics, Hokkaido University, Sapporo 060-8628, Japan

^b National Institute for Materials Science, Tsukuba, Ibaraki 305-0003, Japan

^c Low Temperature Laboratory, Helsinki University of Technology, Espoo, Finland

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Abstract

We succeed in synthesizing NbSe₂ nanotubes along with nanofibers by chemical vapor transportation. They are stable crystalline systems and can be synthesized reproducibly in a nearly equilibrium reacting process. We have investigated these nanosize structures of NbSe₂ by transmission electron microscopy and electron diffraction. Both of the structures have a similar size of 100–200 nm in diameter. While nanotubes consist of rolled-up NbSe₂ layers, nanofibers are a pile of thin flat layers. We propose a mechanism of the formation of NbSe₂ nanotubes and nanofibers on the basis of deselenidative transition from a NbSe₃ fiber-shaped crystal. We also measured electrical resistance of the nanofibers with conductive atomic force microscopy and demonstrated that the material show metallic behavior at room temperature.

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1. Introduction

The discoveries of fullerenes [1], carbon nanotubes (CNT's) [2], and Möbius crystals [3] as topological forms of matter have opened a challenging field covering over solid state physics, chemistry and materials science with wide spectra of possible applications. Topological effects, like the Berry phase [4,5], originating from system geometry have attracted much attention both theoretically and experimentally.

On the other hand, CNT is regarded as a prospective replacement of traditional semiconductor-based devices for constructing integrated circuits because of its characteristic size of nanometers. The nanometer-scale size of CNT offers not only faster operation and lower power consumption of a circuit, but also nontraditional mesoscopic devices, for instance single electron transistors. A superconducting or charge-density-wave (CDW) nanotube creates possibilities for device design for

nanotube circuits. However, the nanoscale regime has not been studied for superconductor and CDW conductor systems, in particular, many aspects of nanoscale CDW dynamics are still unknown [6]. Moreover, the interplay between topological effects and downsized effects of these collective quantum phenomena (CDW and superconductor) are imperious themes because of their connection to the fundamental understanding of quantum mechanics as well as the potential for device construction.

To investigate these effects, we have chosen NbSe₂ for constructing tubular nanostructure. Möbius crystal of NbSe₃ have been the only other topological material of CDW compound so far. While NbSe₃ has a one-dimensional chain structure, which makes it possible to form a Möbius ring, NbSe₂ have a graphite-like layered structure, which is responsible for the formation of topological materials such like CNT's. NbSe₂ exhibits CDW transition at 33 K, and becomes superconductor below 7.2 K. These properties make the matter a promising candidate of a superconducting and/or CDW nanotube [7], both of which will be a valuable member to the known nanotube family: a normal metal or a

* Corresponding author.

E-mail address: tsuneta@eng.hokudai.ac.jp (T. Tsuneta).

URL: <http://exp-ap.eng.hokudai.ac.jp>.

semiconductor (carbon nanotubes), and insulators (BN [8], MoS₂ [9] and WS₂ [10] nanotubes). However, NbSe₂ nanotubes were so far merely produced under electron irradiation with extremely high energy [11], while nanotubes of MoS₂ and WS₂, whose crystal structures are similar to NbSe₂, were synthesized by various chemical methods. In this study, we present evidence of NbSe₂ multi-wall nanotubes with diameters of 30–200 nm formed by a nearly equilibrium chemical reaction in a controllable way. Also, we propose a formation mechanism of the NbSe₂ nanotube based on transition from a NbSe₃ nanofiber.

2. Experimental procedures

We abstracted nanosize objects from NbSe₂ powder synthesized by direct chemical vapor transportation (CVT) method through following procedures. We put high-purity niobium (4N) and selenium (4N) in evacuated (10⁻⁶ Torr) silica ampoules as initial materials. The ampoules are then heated to the maximum temperature of 800 °C by a rate of 10 °C/min inside a furnace that has a spatial gradient of 1 °C/cm. Note that this method can be applied to synthesize niobium selenides with different composition, such as NbSe₃, by setting appropriate reaction temperature. After an hour of reaction, the ampoules are quenched to room temperature. Obtained NbSe₂ powder is suspended in dichloroethane or isopropyl alcohol by sonication of few minutes, and then nanosize particles in the dispersion are deposited on a substrate.

3. Results and discussions

3.1. Nanotubes and nanofibers

Fig. 1(a) shows a transmission electron microscope (TEM) image of a NbSe₂ nanotube found in deposition.

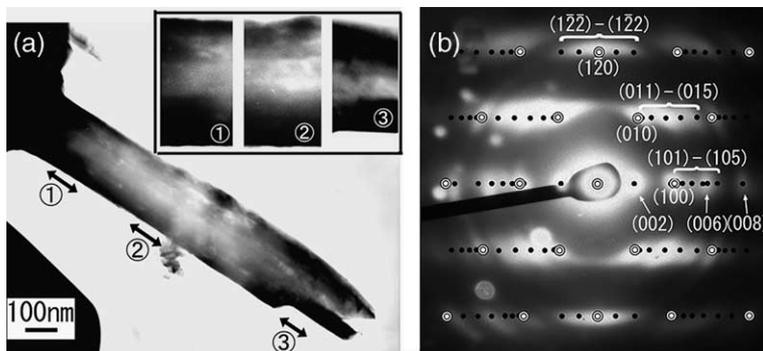


Fig. 1. (a) A TEM micrograph of a 200 nm wide, 1.3 μm long open-end nanotube sticking out of a bulk crystal. An internal cavity of 60 nm in width is shown in insets, which are enlarged views of respective parts of the material. (b) Each (*hk*0) diffractions in this TED pattern of the NbSe₂ nanotube is accompanied by (*hkn*) (*n* = 1, 2, 3...) diffractions aligned in an array perpendicular to the longitudinal axis of the material. This aspect is characteristic of a tubular structure.

The 200 nm wide, 1.3 μm long material sticking out of a bulk crystal shows an internal structure. The insets show enlarged views of internal structure from respective parts of the fiber. A transmission electron diffraction (TED) pattern (Fig. 1(b)) of the material has a 2 mm symmetry, and is composed of the spots aligned in rows vertical to the fiber. The crystal structure derived from the pattern is that of a hexagonal with $a/c = 0.27$, agreeing with that of 2H-NbSe₂ (hexagonal, $a/c = 0.274$, $a = 3.444$ Å and $c = 12.552$ Å). Nevertheless the material is not any other niobium-selenides including fiber-shaped compounds NbSe₃, Nb₂Se₃, etc. The diffraction spots can be indexed as shown in Fig. 1(b). The unindexed ones are diffractions by a tiny affix.

The material has clear features of a tubular structure in its TED pattern as follows. In the pattern, each hexagonal (*hk*0) spot accompanies diffraction spots with nonzero *c**-component, (*hkn*) (*n* = 1, 2, 3...), aligned horizontally and outwardly. This aspect is crucial to a tubular structure according to the previous studies on CNT [12]. Hence the structure shown in Fig. 1 is an internal cavity of a width of 60 nm. We estimate the number of layers of the material as 120, which is too much to obtain an atomic image. Also we should point out that all coaxial shells of the tube have the chirality of armchair, i.e. a $\langle 100 \rangle$ direction is toward the longitudinal axis.

We discovered another kind of nanofibers formed along with NbSe₂ tubes. Fig. 2(a) shows typical lattice image of a fiber without any cavity. The shown lattice spacing of 6.44 Å corresponds to interlayer distance of NbSe₂ (6.276 Å). It means that the micrograph depicts the side-surface of a NbSe₂ nanofiber consisting of stacked ribbon-shaped crystal layers. The same structure is verified by a TED pattern (Fig. 2(b)) of another fiber containing only (*hk*0) diffractions. The longitudinal axis of most nanofibers is also along a $\langle 100 \rangle$ axis, as in Fig. 2(b).

We believe that the origin of our NbSe₂ nanotubes is scrolling of nanofibers. Actually, we once observed a

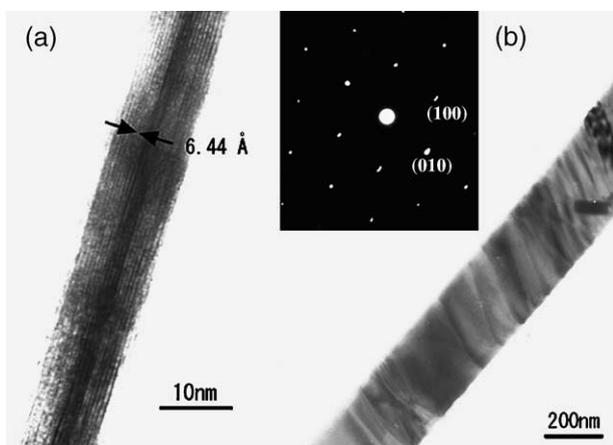


Fig. 2. (a) This TEM image of a nanofiber shows lattice spacing of 6.44 Å that agree with (002) plane of 2H-NbSe₂. (b) A TEM image of another NbSe₂ nanofiber, whose TED pattern (inset) shows only one set of hexagonal diffractions. Both of the materials are ribbon-shaped NbSe₂ nanofibers having the *a*-*b* plane as its facet.

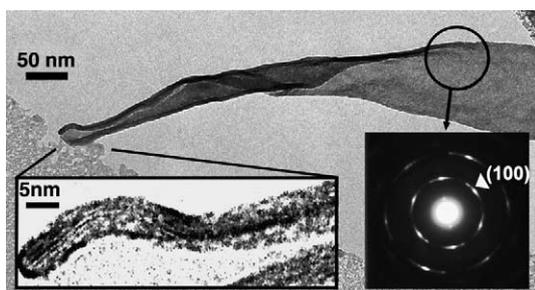


Fig. 3. A TEM micrograph of a part of a 110 nm wide, 2 μm long NbSe₂ nanofiber that began folding under an electron irradiation. The left end was made into a scroll (left inset). Its TED pattern (right inset) agrees with the *a**-*b** plane of NbSe₂.

fiber irradiated by an electron beam began scrolling and eventually formed a tube-like structure. Here we present a TEM image of the “intermediate” structure between nanotubes and ribbon-shaped nanofibers (Fig. 3). The right part of the 110 nm wide, 2 μm long fiber has the shape of a thin ribbon. Its TED pattern (right inset) indicates a hexagonal pattern with $d_{100} = 2.97 \text{ \AA}$, and agrees with the *a**-*b** plane of NbSe₂. However, the rest of the material is folded and the end of the fiber is almost completely scrolled, just like scroll-type CNT’s [13].

3.2. Formation model

Next, we present a model of nanotube formation via intermediate nanofiber (Fig. 4 shows a schematic). Usually a fiber-shaped crystal of NbSe₂ cannot be formed by an equilibrium growth, because the largest

facet should have six-fold rotation symmetry. However, we found the possibility of the transition from a NbSe₃ fiber into a NbSe₂ fiber by deselenidation. NbSe₃ has a chain-like structure along the *b*-axis and always makes a fiber-shaped crystal. A deselenidative transition from NbSe₃ chains to a NbSe₂ layer would be achieved through union of an array of parallel chains into a plane (the configuration of Nb atoms along a chain is kept unchanged) because the Nb-Nb distance along a NbSe₃ chain (3.478 Å) is very close to that within a NbSe₂ plane (3.444 Å) and the intra-chain bonding is strong compared to the inter-chain bonding. As a result, a NbSe₃ fiber made of parallel chains becomes a NbSe₂ fiber made of stacked strips.

This model is consistent with experimental results. We observed that the *a*-axis of most NbSe₂ fibers is along the longitudinal direction. This fact agrees with the atomic configuration of our model, in which the *a*-axis of NbSe₂, the direction of Nb-Nb bonds, replaces the *b*-axis of NbSe₃ that is along the length of a fiber as well as Nb-Nb bonds. Although we supposed presence of NbSe₃ in first place, it is reasonable that NbSe₃ are synthesized first during heating process, because temperature reaches the optimum reaction temperature for NbSe₃ (740 °C) earlier than that for NbSe₂ (800 °C).

In expansion of this model, the deselenidation can also cause curvature to a NbSe₂ fiber. The deselenidation would propagate from the surface to inner layers. In the transient stage of the propagation, a few NbSe₂ layers cling to surface of NbSe₃. On this occasion, discord between Nb-Nb distance within a NbSe₂ layer and that across NbSe₃ chains eventuate in a stress that makes NbSe₂ layers scrolled lengthwise (see Fig. 4(d) for an illustration). A similar mechanism is known for kaolinite minerals [14] that have a cylindrical structure originated from discord in in-plane atomic distance between adjacent layers.

3.3. Electric properties

Preliminary studies on electric properties of the NbSe₂ nanofibers were performed in room temperature. Standard electron beam (e-beam) lithography and focused ion beam (FIB) deposition techniques were used to fabricate electrodes on the fibers. By e-beam lithography, four fingers of gold film with adhesive layer of titanium were deposited on the fibers. However, we have not succeeded by e-beam lithography to make electrical conduction between the electrode and the sample to date. This is probably due to a thin insulating layer on the surface of the fibers because we could make a good contact by FIB deposition of tungsten with high acceleration voltage. Since there is a crucial disadvantage of the FIB-deposited tungsten due to its superconducting

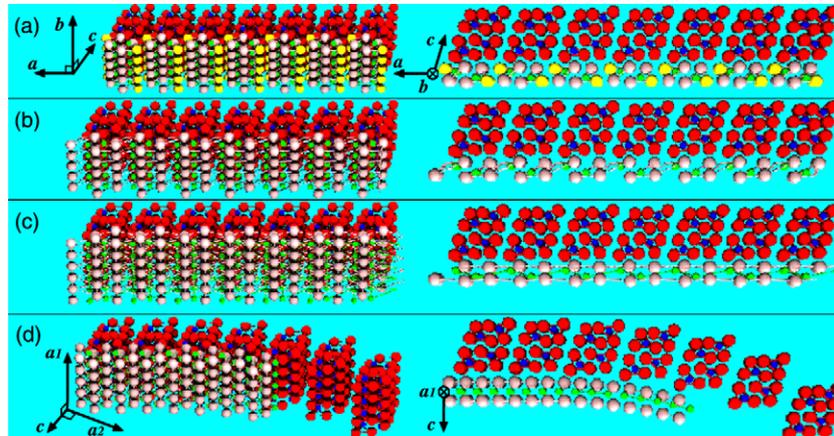


Fig. 4. Our model of deselenidative transition from a NbSe_3 fiber to a NbSe_2 nanotube. The outermost layer, which we suppose to transit into NbSe_2 first, is colored differently. (a) A NbSe_3 fiber composed of one-dimensional molecular chains along the b -axis. The yellow Se atoms are to be removed by deselenidation. (b) The voids produce inter-chain attraction. (c) The chains unite into a two-dimensional layer of NbSe_2 . (d) Because of discord between inter-chain distance of NbSe_3 and in-plane atomic distance of NbSe_2 , the NbSe_2 layer at surface shrinks dragging the inner NbSe_3 layers. Consequently, a scrolling NbSe_2 nanofiber is formed.

nature, e-beam lithography should be developed for low-temperature measurement. From the measurement of the FIB deposited fiber, in-plane resistivity was calculated as $7 \times 10^{-7} \Omega\text{m}$.

In addition to these methods for making electrodes, we used the tip of the AFM as an electrode directly placed on the sample. The conductive tip is made of silicon single crystal with platinum coat. The NbSe_2 fibers were deposited on an indium film of a thickness of 200 nm. The performance of this system was tested with multiwall CNT's, and confirmed that the resistances were in agreement with literature values. By applying the load of 200 nN at the AFM tip end to penetrate the surface insulating layer, a current of 5×10^{-9} A flowed at 1×10^{-3} V bias, corresponding to the resistance of 200 k Ω . A crude estimation of the resistivity ranges 10^{-3} – $10^{-2} \Omega\text{m}$. This value is relatively in good agreement with that perpendicular to the c -axis, $4 \times 10^{-5} \Omega\text{m}$.

4. Summary

We have presented evidence of the formation of NbSe_2 nanotubes and nanofibers by chemical vapor transportation method. And we have proposed a model of the formation of nanotubes and nanofibers via transition from a NbSe_3 nanofiber. Also, we confirmed metallic conductivity of the nanostructures in room temperature.

It is an important problem whether the NbSe_2 nanotube can be a superconductor, because superconductivity is affected by topology of the system. Electron beam holography with cryogenic system will reveal nature of the electron properties of such the “topological materials”.

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